



140V PNP LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > -140V
- Small Form Factor Thermally Efficient Package. **Enables Higher Density End Products**
- I_C = -4A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -120 \text{mV} @ I_C = -1 \text{A}$
- R_{SAT} = 72m Ω for a Low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI®3333-8
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

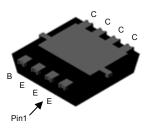
Applications

- Motor Driving
- Line Switching
- High-Side Switches

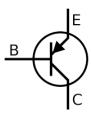
PowerDI3333-8 (SWP) (Type UX)







Bottom View



Device Symbol

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTP03140BFG-7	2K2	7	12	2000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- and Lead-free.

 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/products/packages.html.

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K2= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-4	Α
Peak Pulse Current	I _{CM}	-10	A

The rmal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.07	W
Power Dissipation	(Note 6)	P_{D}	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{OJA}	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{ÐJL}	6	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C	

ESD Ratings (Note 9)

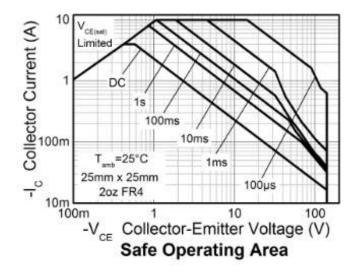
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

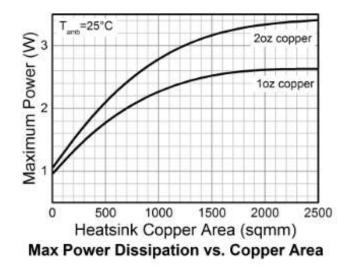
Notes:

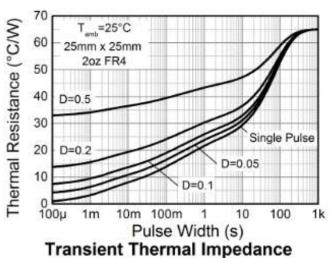
- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- S. To a device friodined with the collector tab of MixT RAP-CB, device is meast
 Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.
 Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.
 Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

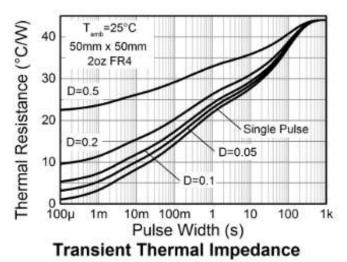


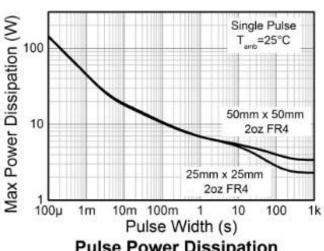
Thermal Characteristics and Derating Information

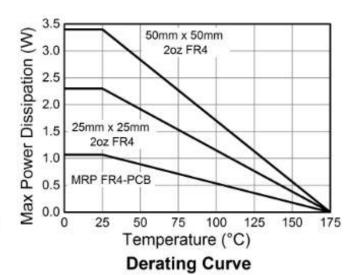














Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

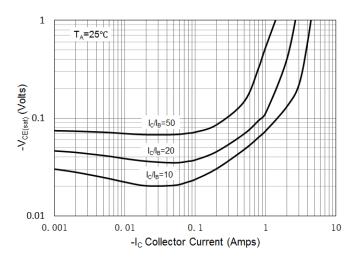
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-180	-216	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CER}	-180	_	_	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-140	-164	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.3	_	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	-	-1	-20	nA	V _{CB} = -150V
Collector Cut-Off Current		-	-0.1	-10	μA	V _{CB} = -150V, T _A = +125°C
Collector Cut-Off Current	I _{CER}	-	-2	-20	nA	V _{CB} = -150V
Collector Cut-Off Current	R≤1kΩ	-	-0.3	-10	μA	V _{CB} = -150V, T _A = +125°C
Emitter Cut-Off Current	I _{EBO}	-	-1	-10	nA	V _{EB} = -6V
	<u>_</u>	100	165	_	_	$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Transfer Static Ratio (Note 10)		100	154	300	_	$I_C = -1A$, $V_{CE} = -5V$
DC Current Transfer Static Ratio (Note 10)	h _{FE}	45	65	_	_	$I_C = -3A$, $V_{CE} = -5V$
		1	5	_	_	$I_C = -10A$, $V_{CE} = -5V$
	\/	ı	-37	-60	mV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 10)		-	-47	-80	mV	$I_C = -0.5A$, $I_B = -50mA$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	_	-72	-120	mV	I _C = -1A, I _B = -100mA
		1	-200	-360	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	ı	-918	-1040	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	-	-802	-930	mV	$I_C = -3A$, $V_{CE} = -5V$
Transitional Frequency	f _T	_	120	_	MHz	I _C = -100mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	_	33	_	pF	V _{CB} = -10V, f = 1MHz
	t _{delay}	_	9.7	_	ns	
Switching Characteristics	t_{rise}	_	200	_	ns	$V_{CC} = -50V, I_{C} = -1A,$
Switching Characteristics	t _{storage}	_	1500	_	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
	t _{fall}	_	137	_	ns	

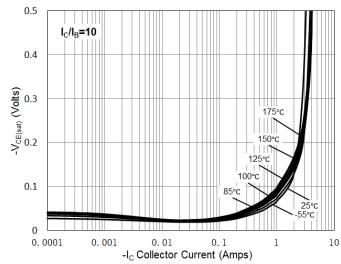
Note:

10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



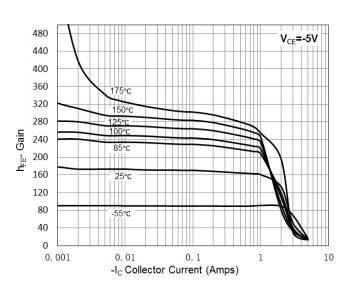
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

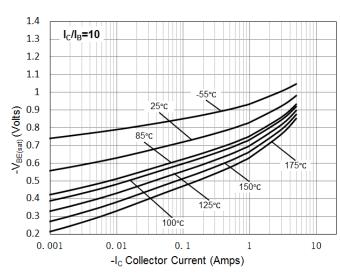




 $V_{\text{CE(sat)}}vs I_{\text{C}}$

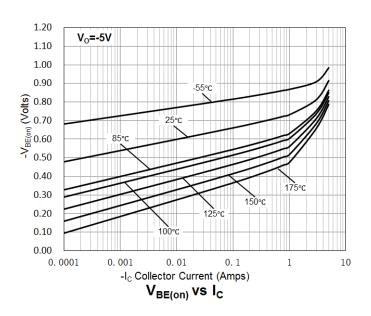
V_{CE(sat)}vs I_C





h_{FE} vs I_C

V_{BE(sat)} vs I_C

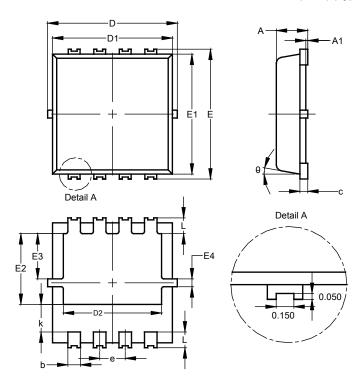




Package Outline Dimensions

Please see https://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

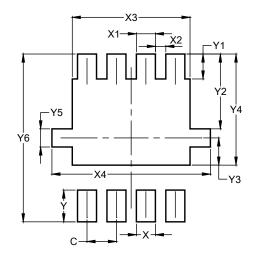


PowerDI3333-8 (SWP)				
(Type UX)				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05	-	
b	0.25	0.40	0.32	
С	0.10	0.25	0.15	
D	3.20	3.40	3.30	
D1	2.95	3.15	3.05	
D2	2.30	2.70	2.50	
E	3.20	3.40	3.30	
E1	2.95	3.15	3.05	
E2	1.60	2.00	1.80	
E3	0.95	1.35	1.15	
E4	0.10	0.30	0.20	
е	_	-	0.65	
k	0.50	0.90	0.70	
L	0.30	0.50	0.40	
θ	0°	12°	10°	
All Dimensions in mm				

Suggested Pad Layout

Please see https://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.600		
X4	3.500		
Υ	0.700		
Y1	0.550		
Y2	1.650		
Y3	0.600		
Y4	2.450		
Y5	0.400		
Y6	3.700		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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